
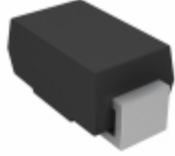
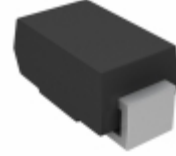
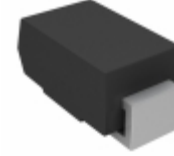
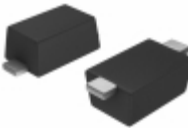
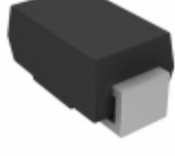
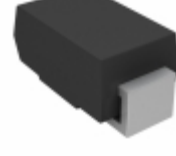
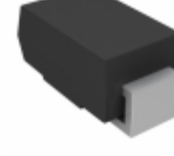
	<p>US1AHE3/5AT</p>
	<p>Hersteller-Teilenummer: US1AHE3/5AT</p> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <p>Teil der Beschreibung: DIODE GEN PURP 50V 1A DO214AC</p> <p>Datenblätter: 1.US1AHE3/5AT.pdf 2.US1AHE3/5AT.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 345000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	US1AHE3/5AT
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 50V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	345000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1V @ 1A
Strom - Sperrleckstrom @ Vr	10µA @ 50V
Spannung - Sperr (Vr) (max)	50V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	50ns
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	15pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

US1AHE3/5AT ist neu im Original, Suche US1AHE3/5AT Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie US1AHE3/5AT Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage US1AHE3/5AT: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>US1AF Original US1AF Original</p>	 <p>US1AHE3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 50V 1A DO214AC</p>	 <p>US1AHE3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 50V 1A DO214AC</p>	 <p>US1AHE3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 50V 1A DO214AC</p>
 <p>US1AFA AMI Semiconductor / ON Semiconductor DIODE GEN PURP 50V 1A SOD123FA</p>	 <p>US1AHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 50V 1A DO214AC</p>	 <p>US1AHE3_A/I Electro-Films (EFI) / Vishay DIODE GEN PURP 50V 1A DO214AC</p>	 <p>US1AHE3_A/H Vishay / Semiconductor - Diodes Division DIODE FAST REC 50V 1A DO214AC</p>

heiße Teile

Mehr

- | | | | | |
|---------------|------------------------|---------------|---------------|---------------|
| ⊕ US168ELD | ➔ US168ESE | ➔ US1881ESO | D US1881KSE | ➔ US1881KSO |
| ⊕ US1881KUA | ⊕ US1881KUA-AAA-000-BU | D US1881LSO | ➔ US1A-13-F | ➔ US1A-E3/5AT |
| ⊕ US1A-E3/5AT | ⊕ US1A-E3/61T | ⊕ US1A-E3/61T | ➔ US1A-M3/61T | ➔ US1A-M3/61T |
| D US1AHE3/5AT | ⊕ US1AHE3/61T | ⊕ US1AHE3/61T | ⊕ US1B-13-F | ➔ US1B-E3/5AT |
| ➔ US1B-E3/5AT | ➔ US1B-E3/61T | ⊕ US1B-E3/61T | ⊕ US1B-M3/61T | ➔ US1B-M3/61T |
| ➔ US1BHE3/5AT | ➔ US1BHE3/5AT | D US1BHE3/61T | ⊕ US1BHE3/61T | ⊕ US1C-E3/61T |
| ⊕ US1D-13-F | D US1D-E3/61T | ➔ US1D-E3/61T | ➔ US1D-M3/61T | ➔ US1D-M3/61T |
| ⊕ US1DWF-7 | ⊕ US1DWF-7 | ➔ US1G-13-F | ➔ US1G-E3/61T | ➔ US1G-E3/61T |
| ⊕ US1G-M3/61T | ⊕ US1G-M3/61T | ⊕ US1G/11T | D US1GHE3/5AT | ➔ US1GHE3/5AT |
| ➔ US1GHE3/61 | ⊕ US1GHE3/61T | ⊕ US1GHE3/61T | ⊕ US1GHE3_A/H | ➔ US1GHE3_A/H |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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